

Performance Parameters

$$I_{rms} = \sqrt{\frac{1}{T} \int i^2 dt}$$
$$CrestFactor = \frac{V_{peak}}{V_{rms}}$$
$$DistortionFactor = \frac{I_{1rms}}{I_{rms}} = \frac{1}{\sqrt{1 + THD^2}}$$

ϕ : phase difference between fundamentals of current and voltage

$$DisplacementPowerFactor = \cos(\phi)$$
$$TruePowerFactor = \frac{P}{S} = DPF \frac{I_{1,RMS}}{I_{RMS}}$$
$$THD = \sqrt{\left(\frac{I_{rms}}{I_{1rms}}\right)^2 - 1}$$

Single Phase Diode Rectifier

$$V_{av} = \frac{2\sqrt{2}V_s}{\pi} (Fullwave), V_{av} = \frac{\sqrt{2}V_s}{\pi} (Halfwave)$$

u : commutation period

$$\cos(u) = 1 - \frac{2\omega L_s I_d}{\sqrt{2}V_s} \quad (Full\ wave)$$
$$\cos(u) = 1 - \frac{\omega L_s I_d}{\sqrt{2}V_s} \quad (Half\ wave)$$
$$A_u = \int_0^u V_s \sqrt{2} \sin(\omega t) d\omega t = \omega L_s I_d$$

Commutation Loss : $\frac{2\omega L_s I_d}{2\pi}$ (Full wave)
 $\frac{\omega L_s I_d}{2\pi}$ (Half wave)

$I_{d,avg} = \frac{\int_b^f i(\theta) d\theta}{\pi}$

$I_{d,shortcircuit} = \frac{V_s}{\omega L_s}$

for Flyback

$$\hat{I}_{Sw,peak} = \frac{1}{(1-D)} \frac{N_2}{N_1} I_o + \frac{N_1}{N_2} \frac{(1-D) T_s V_o}{2L_m}$$
$$\hat{V}_{Sw,peak} = V_d + \frac{N_1}{N_2} V_o = \frac{V_d}{(1-D)}$$

Three Phase Rectifier

- Half Wave
- Full Wave

Full Bridge Rectifier Average Output V_s :rms value of source voltage

$$V_{av} = \frac{3\sqrt{6}V_s}{2\pi} = \frac{3\sqrt{2}V_{ll}}{2\pi}$$
$$V_{av} = \frac{3\sqrt{6}V_s}{\pi} - \frac{3\omega L_s I_d}{\pi}$$

Comparison of Rectifiers

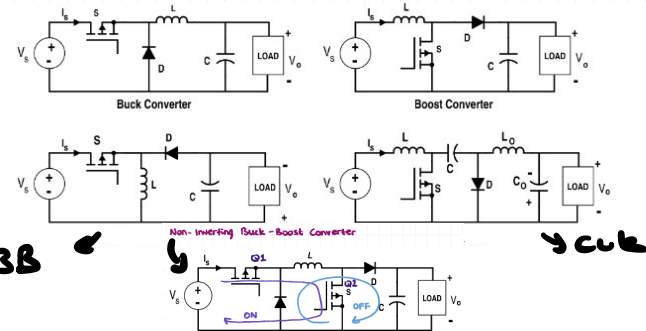
| Type | Vout | ΔV_{out} | f_{ripple} |
|---------------------|---|---|--------------|
| Single Phase | $\frac{2\sqrt{2}}{\pi} V_{ph} = 207\text{ V}$ | $\sqrt{2} V_{ph} = 325\text{ V}$ | 100 Hz |
| 3-phase Half Bridge | $\frac{3\sqrt{2}}{2\pi} V_{l-l} = 270\text{ V}$ | $\frac{\sqrt{2}}{2} V_{ph} = 162.5\text{ V}$ | 150 Hz |
| 3-phase Full Bridge | $\frac{3\sqrt{2}}{\pi} V_{l-l} = 540\text{ V}$ | $(1 - \frac{\sqrt{3}}{2}) \sqrt{2} V_{l-l} = 75.8\text{ V}$ | 300 Hz |

Voltage Ripple of Buck Converters

$$\Delta Q = \frac{\Delta I_L}{2} \cdot \frac{T_s}{2} = \frac{T_s \Delta I_L}{8} \quad \Delta V_o = \frac{\Delta Q}{C} \Rightarrow \Delta V_o = \frac{T_s \Delta I_L}{8C}$$
$$\Delta I_L = \frac{V_o (1-D) T_s}{L} \Rightarrow \Delta V_o = \frac{T_s V_o (1-D) T_s}{8LC} \Rightarrow \frac{\Delta V_o}{V_o} = \frac{(1-D) T_s^2}{8LC}$$

using off-time (1-D) $\Rightarrow I_L = \frac{1}{L} \int V_o dt$

$$T_s = \frac{1}{f_s}, f_c = \frac{1}{2\pi LC} \Rightarrow LC = \frac{1}{4\pi^2 f_c^2} \Rightarrow \frac{\Delta V_o}{V_o} = \frac{(1-D) \cdot 4\pi^2 f_c^2}{8 f_s^2} \Rightarrow \frac{\Delta V_o}{V_o} = \frac{(1-D) \pi^2}{2} \left(\frac{f_c}{f_s}\right)^2$$



Buck Converter (Step-Down)

Gain: $V_o = DV_d$
 $V_L = V_d - V_o$ (On), $V_L = -V_o$ (Off)

Inductor Ripple: $\Delta I_L = \frac{V_o(1-D)}{L f_s}$

Voltage Ripple: $\frac{\Delta V_o}{V_o} = \frac{1-D}{8LC f_s^2}$

CCM/DCM Boundary: $I_{LB} = \frac{\Delta I_L}{2} = \frac{DT_s(V_d)(1-D)}{2L}$

CCM/DCM Boundary: $L_{min} = \frac{DT_s(V_d - V_o)}{2I_{LB}} = \frac{RT_s(1-D)}{2}$

Boost Converter (Step-Up)

Gain: $V_o = \frac{V_d}{1-D}$
 $V_L = V_d$ (On), $V_L = V_d - V_o$ (Off)

Inductor Ripple: $\Delta I_L = \frac{V_d D}{L f_s}$

Voltage Ripple: $\frac{\Delta V_o}{V_o} = \frac{D}{RC f_s}$

CCM/DCM Boundary: $I_{LB} = \frac{\Delta I_L}{2} = \frac{V_d D T_s}{2L}$

Min Inductance: $L_{min} = \frac{D(1-D)^2 R}{2f_s}$

Buck-Boost Converter

Gain: $V_o = V_d \frac{D}{1-D}$
 $V_L = V_d$ (On), $V_L = -V_o$ (Off)

Inductor Ripple: $\Delta I_L = \frac{V_d D}{L f_s}$

Voltage Ripple: $\frac{\Delta V_o}{V_o} = \frac{D}{RC f_s}$

CCM/DCM Boundary: $I_{LB} = \frac{\Delta I_L}{2} = \frac{V_d D T_s}{2L}$

Min Inductance: $L_{min} = \frac{(1-D)^2 R}{2f_s}$

Cuk Converter

Gain: $V_o = -V_d \frac{D}{1-D}$
 $V_{L1} = V_d$ (On), $V_{L1} = V_d - V_{C1}$ (Off)

Inductor Ripple (L_1): $\Delta I_{L1} = \frac{V_d D}{L_1 f_s}$

Inductor Ripple (L_2): $\Delta I_{L2} = \frac{V_d D}{L_2 f_s}$

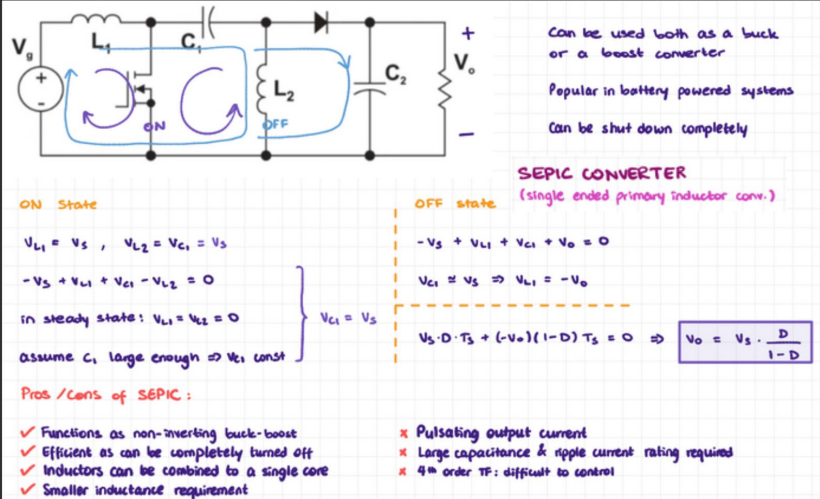
Voltage Ripple (C_o): $\frac{\Delta V_o}{V_o} = \frac{1-D}{8L_2 C_2 f_s^2}$

CCM/DCM Boundary: $I_{LB1} = \frac{V_d D T_s}{2L_1}$ (for L_1)

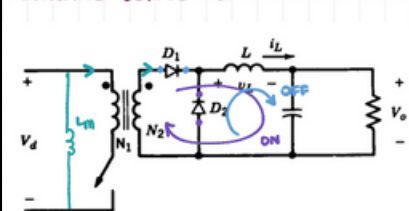
Min Inductance (L_1): $L_{1,min} = \frac{(1-D)^2 R}{2D f_s}$

Min Inductance (L_2): $L_{2,min} = \frac{(1-D) R}{2f_s}$

Cuk Feature: Input and Output currents are continuous (low ripple) due to inductors on both sides.



FORWARD CONVERTER

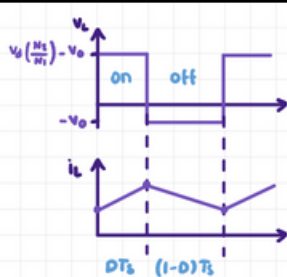


ON State

$$V_L = V_d \cdot \left(\frac{N_2}{N_1} \right) - V_o$$

OFF State

$$V_L = -V_o$$



The energy stored in L_m , if discharged through the switch, could destroy the MOSFET. To prevent this, a snubber circuitry could be added but would cause important losses. A practical solution is to add an extra winding:

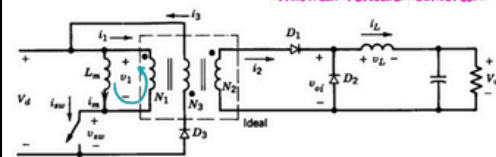
$$\left(V_d \left(\frac{N_2}{N_1} \right) - V_o \right) D = V_o (1-D)$$

$$V_d \cdot \frac{N_2}{N_1} \cdot D - V_o D = V_o - V_o D$$

$$V_o = V_d \frac{N_2}{N_1} D$$

Like a buck converter with added turns ratio

Practical Forward Converter:



With this implementation, the energy stored in L_m is discharged to the source.

$$i_1 = -i_{Lm}$$

$$N_1 i_1 = N_2 i_2 - N_3 i_3$$

$$N_1 i_1 = -N_3 i_3$$

Transformer Reset: $t_m < (1-D)T_s$

Max Duty Cycle: $D_{max} = \frac{1}{1 + (N_3/N_1)}$

$$V_{Lm} = V_1 = -V_s \frac{N_1}{N_3} = -L_m \frac{di_{Lm}}{dt}$$

$$\frac{di_{Lm}}{dt} = -\frac{V_s}{L_m} \frac{N_1}{N_3}$$

ON State

$$V_1 = V_s$$

$$V_2 = V_s \frac{N_2}{N_1} = V_s \frac{N_2}{N_1}$$

$$V_3 = V_s \frac{N_3}{N_1} = V_s \frac{N_3}{N_1}$$

$$V_{D3} = -V_s - V_3 < 0 \Rightarrow D_3 \text{ is off}$$

$$V_{Lm} = V_s \quad \Delta i_{Lm} = \frac{V_s D T_s}{L_m}$$

$$i_{sw1} = i_1 + i_{Lm}$$

OFF State

$$i_{Lm} = -i_1$$

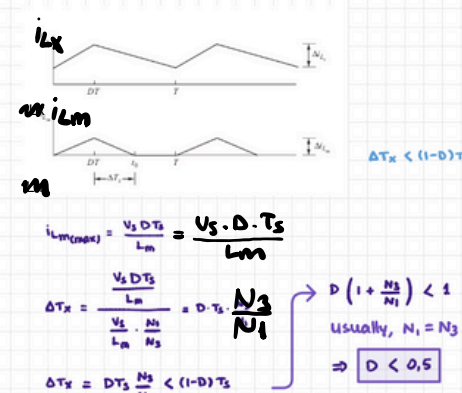
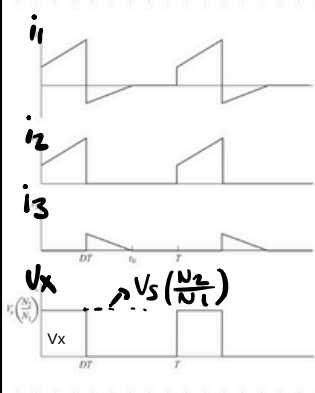
$$V_1 = -V_s$$

$$V_2 = V_s \frac{N_2}{N_1} = -V_s \frac{N_2}{N_1}$$

$$V_3 = V_s \frac{N_3}{N_1} = -V_s \frac{N_3}{N_1}$$

$$N_1 i_1 = N_2 i_2 - N_3 i_3 \quad N_1 i_1 = -N_3 i_3$$

$$i_3 = -\frac{N_1}{N_3} i_1$$



Advantages/Disadvantages Over Flyback

- ✓ Better use of transformer (direct & higher power transfer)
- ✓ Gapless core can be used (higher $L_m \rightarrow$ less ripple)
- ✓ Output inductor + diode ensure continuous output current

Practical Forward Converter:

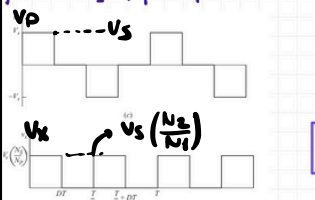
- ✗ Possibly increased cost
- ✗ Gain changes a lot in DCM & may require closed-loop control
- ✗ Higher voltage requirement for MOSFET

FULL BRIDGE ISOLATING CONVERTER

Operation very similar to push-pull conv.

Switches 1 & 2 are operated together just as SW_1 of push-pull.

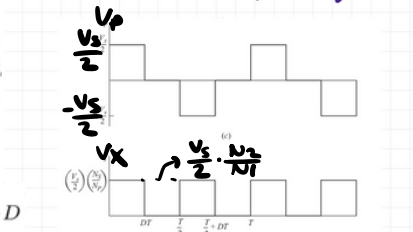
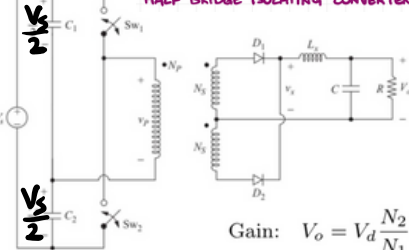
Switches 3 & 4 are operated together just as SW_2 of push-pull.



$$V_o = 2 V_s \frac{N_2}{N_1} D \quad D < 0.5$$

HALF BRIDGE ISOLATING CONVERTER

Very similar to full-wave converter. Less switches are used: output voltage halved



$$\text{Gain: } V_o = V_d \frac{N_2}{N_1} D$$

FLYBACK CONVERTER

ON State

Diode is reverse biased, hence OFF $\Rightarrow i_2 = 0 \Rightarrow i_1 = 0$
 \Rightarrow transformer acts as a mere inductor
 L_m is charging (as in buck-boost)

OFF State

$$V_{Lm} = V_s$$

$$V_{sw} = V_s + V_o \left(\frac{N_1}{N_2} \right)$$

FLYBACK CONVERTER

$$\text{Gain: } V_o = V_d \frac{N_2}{N_1} \frac{D}{1-D}$$

$$\text{Inductor Voltage: } V_L = V_d \text{ (On), } V_L = -\frac{N_1}{N_2} V_o \text{ (Off)}$$

$$\text{Inductor Ripple: } \Delta I_L = \frac{N_1}{L_m N_2} (1-D) V_o$$

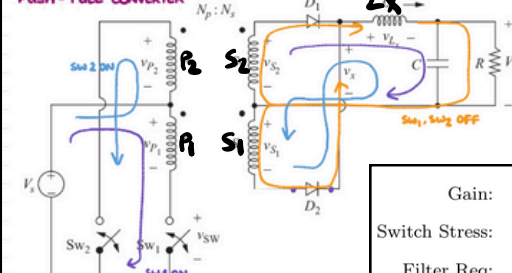
$$\text{Voltage Ripple: } \frac{\Delta V_o}{V_o} = \frac{N_1}{8 f_s C L_m N_2} (1-D)$$

$$\text{CCM/DCM Boundary: } I_{LB} = \frac{\Delta I_L}{2} = \frac{(1-D) V_o T_s N_1}{2 L_m N_2}$$

There are multiple ways to calculate the voltage relations of a flyback. It can be done using:

- transformer flux
- steady state current
- voltage-seconds balance

PUSH-PULL CONVERTER



The design uses a center-tap transformer (turns ratio can be adjusted)

The converter has 3 operating regions:

$$\text{Gain: } V_o = 2 V_d \frac{N_2}{N_1} D$$

$$\text{Switch Stress: } V_{sw} = 2 V_d$$

$$\text{Filter Req: } \Delta I_L = \frac{V_o (0.5 - D)}{L f_s} \quad (\text{for } D < 0.5)$$

SW1 ON, SW2 OFF

D_1 conducts, D_2 reverse biased

$$V_L = V_x - V_o = \frac{N_2}{N_1} V_s - V_o$$

i_L increases linearly

SW2 ON, SW1 OFF

Symmetrical operation

$$V_L = V_x - V_o = \frac{N_2}{N_1} V_s - V_o$$

i_L increases linearly

Both switches OFF

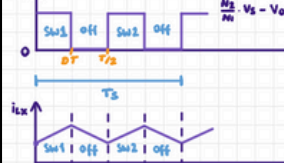
For a period Δ , D_1 & D_2 conduct

$$I_{D1} = I_{D2} = 0.5 I_L$$

$V_x = 0 \Rightarrow V_L = -V_o$

inductor feeds the load

Waveform is repeating every $T_s/2$



$$D T_s + \Delta = T_s/2$$

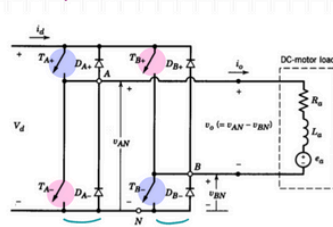
$$\Delta = \frac{(1-2D)}{2} T_s$$

$$\frac{V_o}{V_d} = 2 \frac{N_2}{N_1} D$$

Advantages/Disadvantages:

- ✓ Better usage of the core compared to Forward conv.
- ✓ Better B-H curve: uses both +/- regions
- ✗ Need to control 2 switches

Control of 4 Quadrant Converters



Bipolar Voltage Switching

T_{A+} & T_{B-} are ON or OFF together

T_{A-} & T_{B+} are complementary to T_{A+} , T_{B-}

Output can be $+V_d$ or $-V_d$

Average Output according to switch durations

Uni-Polar Voltage Switching

T_{A+} & T_{B+} controlled separately

T_{A-} & T_{B-} complementary to T_{A+} , T_{B+}

Output can be $+V_d$, 0, $-V_d$

$V_o = 0$ if two (+) or two (-) are ON

The output relation Δ is the same in both cases:

$$V_o = V_d \frac{V_{control}}{V_m}$$

However, the ripple is lower & efficiency is higher in the uni-polar case as the voltage level does not have to be negative to decrease the average, instead it can be zero (0).

MAGNETIC DESIGN

For the same flux density, more energy can be stored with a material of lower permeability (μ). When designing a core, air gaps can intentionally be added to increase the energy storage capacity.

Ferrite vs Powder Cores

Ferrite cores have sharp, powder cores have soft saturation
 Powder cores are usually smaller
 Powder cores' magnetic properties are less dependent on temperature
 Powder cores have higher inductance tolerances

$$R = \frac{l}{\mu A}$$

$$L = \frac{N^2}{R}$$